Reference: Chapter 6 Malvino & Bates Current-Voltage Characteristics of the Biased BJTs  $I_{E} = I_{B} + I_{C}$   $I_{B} \sim \mu A$   $I_{E}, I_{C} \sim m A$   $I_{E}, I_{C} \sim m A$ Emitter-Base Junction: Forward Collector-Base Tunction: Reverse Fate of the electrons entering into the Base region from chances to recombins with holes in the bus ii) The electrons way TB(MA) 20MA/ --come out from the Input characteristics constitute a base culu in) Since the collector-I= 10,Abase junction is reverse, the electrons can be collector. I: Saturation Region I: Active Region (Normal III: Break down Region IV: Cut-off Region Output characteristics I=BI Kegion I is the most useful region of operation. It is edso called linear region of operation of the BJTs. If the BJT is biased in this region, then the collector current follows the base-current. That is, any change happening in the base cht, will directly appear across the collector cht.

Region I & IV are the saturation & Cut-off re	zg wns
Region I & IV are the saturation & Cut-off radio operation of the BJTs, respectively.	
In region I: The BJT is in 'ON' state.	
	Electronic
In region I: The BJT is in 'ON' state.  In region IV: The BJT is in "OFF" state.	Buitch
Whenever, you switch from region-I to IV or	vice-versa
the BJT is switching from ON-stali to OFF-sta	le.
ik .	
=> BT Operating as an "Electronic-Switch".	
Note: In region-III (Breakdown region); the	BJT
Note: In region-III (Breakdown region); the burns out ie, it never return back to a operation.	whal
Devactor -	
Input Terminal:	
$V_{BB} = I_{B}R_{B} + V_{BE}$ $\Rightarrow$ $I_{B} = V_{BB} - V_{BE}$	
Also, if ceverent gain of the BUT is given, i	e, Boc
$T = B \cdot T_0$	
$ \underline{\Gamma}_{c} = \beta \cdot \overline{\Gamma}_{b} $	

Output Terminal:

$$V_{CC} = I_{C}R_{C} + V_{CE}$$

$$V_{CE} = V_{CC} - I_{C}R_{C}$$

$$V_{CE} = V_{CC} - I_{C}R_{C}$$

$$V_{CE} = V_{CC} + V_{CC}$$

$$V_{CE} + V_{CE}$$

$$V_{CE} + V_{CE}$$